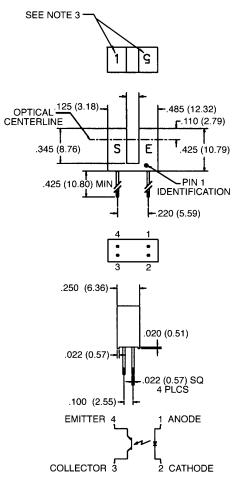


### **SLOTTED OPTICAL SWITCH**

# OPB865N11/OPB865N51/OPB865N55

#### **PACKAGE DIMENSIONS**



#### ST2163

#### NOTES:

- 1. DIMENSIONS ARE IN INCHES (mm).
- 2. TOLERANCE IS ±.010 (.25) UNLESS OTHERWISE SPECIFIED.
- 3. NUMBER INDICATES APERTURE SIZE. (5=.050", 1=.010")

#### APERTURE OPTIONS:

LED	PHOTOTRANSISTOR
.010	.010
.050	.010
.050	.050
	.010 .050

## DESCRIPTION

The OPB865N series of switches is designed to allow the user maximum flexibility in applications. Each switch consists of an infrared emitting diode facing an NPN phototransistor across a .125" (3.18 mm) gap. A unique housing design provides a smooth external surface to prevent dust build-up while molded internal apertures give precise positioning and also provide protection from ambient light interference.

### FEATURES

- Fully enclosed design allows dust and ambient light protection.
- Lead spacing at .220".
- .050" and .010" aperture options.
- PCB mountable.



# **SLOTTED OPTICAL SWITCH**

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C Unless Otherw	rise Specified)
Storage Temperature	-40°C to + 85°C
Soldering: Lead Temperature (Iron) Lead Temperature (Flow)	
INPUT DIODE Continuous Forward Current Reverse Voltage Power Dissipation	5.0 Volt
OUTPUT TRANSISTOR  Collector-Emitter Voltage	

PARAMETER	SYMBOL	MIN.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE					
Forward Voltage	$V_{\scriptscriptstyle F}$		1.70	V	I <sub>F</sub> = 20 mA
Reverse Leakage Current	I <sub>R</sub>		100	μΑ	V <sub>R</sub> = 2.0 V
OUTPUT TRANSISTOR					
Emitter-Collector Breakdown	BV <sub>ECO</sub>	5	-	V	$I_{E} = 100 \ \mu\text{A}, Ee = 0$
Collector-Emitter Breakdown	BV <sub>CEO</sub>	30	_	٧	$I_c = 1.0 \text{ mA}, Ee = 0$
Collector-Emitter Leakage	I <sub>CEO</sub>		100	nA	$V_{ce} = 10.0  V,  Ee = 0$
COUPLED					
On-State Collector Current					
OPB865N11	I <sub>C(ON)</sub>	500	_	μΑ	$I_F = 20 \text{ mA}, V_{CE} = 5 \text{ V}$
OPB865N51	I <sub>C(ON)</sub>	500	_	μΑ	$I_{\scriptscriptstyle F}=$ 20 mA, $V_{\scriptscriptstyle CE}=5~V$
OPB865N55	I <sub>C(ON)</sub>	500	_	μΑ	$I_F = 20 \text{ mA}, V_{CE} = 5 \text{ V}$
Saturation Voltage	V <sub>CE(SAT)</sub>	_	0.40	٧	$I_F = 20$ mA, $I_C = 400 \mu$

## NOTES

- Derate power dissipation linearly 1.67 mW/°C above 25°C.
   RMA flux is recommended.
   Methanol or Isopropyl alcohols are recommended as cleaning agents.
   Soldering iron tip 1/6" (1.6 mm) from housing.



### SLOTTED OPTICAL SWITCH

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